

# Medium Power Transistor (32V, 1A)

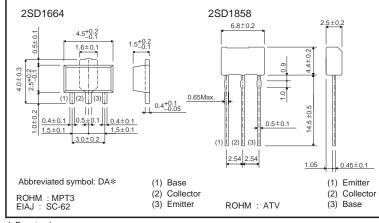
### 2SD1664 / 2SD1858

#### Features

- 1) Low  $V_{CE(sat)} = 0.15V(Typ.)$
- (lc / l<sub>B</sub> = 500mA / 50mA) 2) Compliments 2SB1132 / 2SB1237

•Structure Epitaxial planar type NPN silicon transistor

#### •Dimensions (Unit : mm)



\* Denotes hre

#### ●Absolute maximum ratings (Ta=25°C)

Parameter		Symbol	Limits	Unit	
Collector-base voltage		Vсво	40	V	
Collector-emitter voltage		VCEO	32	V	
Emitter-base voltage		Vebo	5	V	
Collector current		lc	1	A (DC)	
			2	A (Pulse) *1	
Collector power dissipation	0004004	Pc	0.5		
	2SD1664		2	W *2	
	2SD1858		1	*3	
Junction temperature		Tj	150	°C	
Storage temperature		Tstg	-55 to +150	٥C	

\*1 Pw=20ms, duty=1/2

\*2 When mounted on a 40×40×0.7 mm ceramic board.

\*3 When it is mounted on the copper clad PCB (1.7mm thick) with land size for collector 1 square CM or larger.

#### •Electrical characteristics (Ta=25°C)

Parameter	Symbol	Min.	Тур.	Max.	Unit	Conditions
Collector-base breakdown voltage	ВУсво	40	—	_	V	Ic=50μA
Collector-emitter breakdown voltage	BVCEO	32	—	_	V	Ic=1mA
Emitter-base breakdown voltage	ВVево	5	_	_	V	Ιε=50μΑ
Collector cutoff current	Ісво	_	—	0.5	μΑ	Vcb=20V
Emitter cutoff current	Іево	—	—	0.5	μΑ	VEB=4V
DC current transfer ratio	hfe	120	_	390	_	Vce=3V, Ic=100mA
Collector-emitter saturation voltage	VCE(sat)	_	0.15	0.4	V	Ic/I <sub>B</sub> =500mA / 50mA
Transition frequency	f⊤	_	150	_	MHz	Vce=5V, Ie= -50mA, f=100MHz
Output capacitance	Cob	_	15	_	pF	Vcb=10V, Ie=0A, f=1MHz

#### Packaging specifications and hFE

		Package	Taping	
		Code	T100	TV2
Туре	hfe	Basic ordering unit (pieces)	1000	2500
2SD1664	QR		0	_
2SD1858	QR		_	0

#### hFE values are classified as follows :

Item	Q	R
hfe	120 to 270	180 to 390

#### Electrical characteristics curves

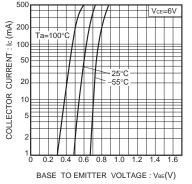


Fig.1 Grounded emitter propagation characteristics

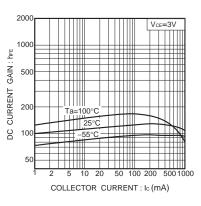
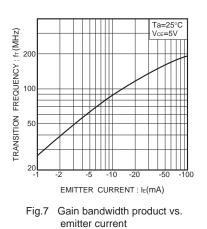
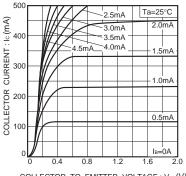


Fig.4 DC current gain vs. collector current (II)





COLLECTOR TO EMITTER VOLTAGE : VCE(V)

Fig.2 Grounded emitter output characteristics

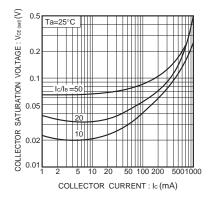
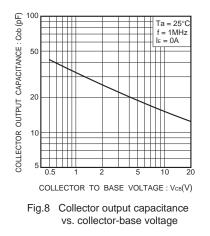


Fig.5 Collector-emitter saturation voltage vs. collector current ( I )



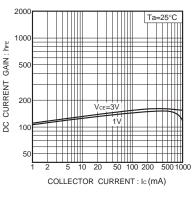


Fig.3 DC current gain vs. collector current (I)

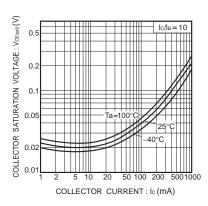
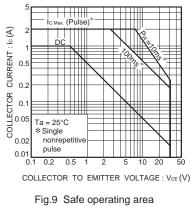


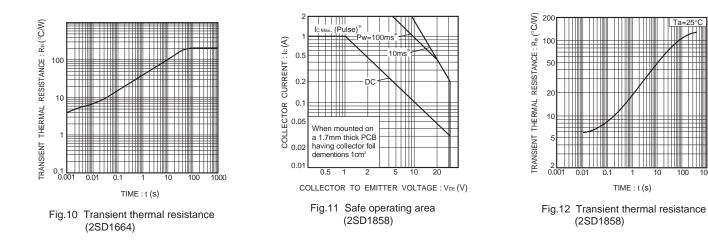
Fig.6 Collector-emitter saturation voltage vs. collector current (II)



(2SD1664)

1000

00



	Notes
1)	The information contained herein is subject to change without notice.
2)	Before you use our Products, please contact our sales representative and verify the latest specifica- tions :
3)	Although ROHM is continuously working to improve product reliability and quality, semicon- ductors can break down and malfunction due to various factors. Therefore, in order to prevent personal injury or fire arising from failure, please take safety measures such as complying with the derating characteristics, implementing redundant and fire prevention designs, and utilizing backups and fail-safe procedures. ROHM shall have no responsibility for any damages arising out of the use of our Poducts beyond the rating specified by ROHM.
4)	Examples of application circuits, circuit constants and any other information contained herein are provided only to illustrate the standard usage and operations of the Products. The peripheral conditions must be taken into account when designing circuits for mass production.
5)	The technical information specified herein is intended only to show the typical functions of and examples of application circuits for the Products. ROHM does not grant you, explicitly or implicitly, any license to use or exercise intellectual property or other rights held by ROHM or any other parties. ROHM shall have no responsibility whatsoever for any dispute arising out of the use of such technical information.
6)	The Products are intended for use in general electronic equipment (i.e. AV/OA devices, communi- cation, consumer systems, gaming/entertainment sets) as well as the applications indicated in this document.
7)	The Products specified in this document are not designed to be radiation tolerant.
8)	For use of our Products in applications requiring a high degree of reliability (as exemplified below), please contact and consult with a ROHM representative : transportation equipment (i.e. cars, ships, trains), primary communication equipment, traffic lights, fire/crime prevention, safety equipment, medical systems, servers, solar cells, and power transmission systems.
9)	Do not use our Products in applications requiring extremely high reliability, such as aerospace equipment, nuclear power control systems, and submarine repeaters.
10)	ROHM shall have no responsibility for any damages or injury arising from non-compliance with the recommended usage conditions and specifications contained herein.
11)	ROHM has used reasonable care to ensur the accuracy of the information contained in this document. However, ROHM does not warrants that such information is error-free, and ROHM shall have no responsibility for any damages arising from any inaccuracy or misprint of such information.
12)	Please use the Products in accordance with any applicable environmental laws and regulations, such as the RoHS Directive. For more details, including RoHS compatibility, please contact a ROHM sales office. ROHM shall have no responsibility for any damages or losses resulting non-compliance with any applicable laws or regulations.
13)	When providing our Products and technologies contained in this document to other countries, you must abide by the procedures and provisions stipulated in all applicable export laws and regulations, including without limitation the US Export Administration Regulations and the Foreign Exchange and Foreign Trade Act.
14)	This document, in part or in whole, may not be reprinted or reproduced without prior consent of ROHM.



Thank you for your accessing to ROHM product informations. More detail product informations and catalogs are available, please contact us.

## ROHM Customer Support System

http://www.rohm.com/contact/